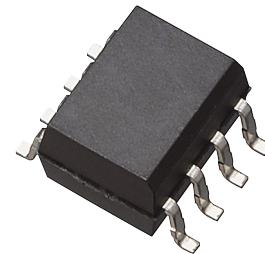


PC457S0NIP0F Series

**High Speed 1Mb/s, High CMR
Mini-flat Package *OPIC Photocoupler**



■ Description

PC457S0NIP0F Series contains a LED optically coupled to an OPIC.

It is packaged in a 8 pin mini-flat.

Input-output isolation voltage(rms) is 3.75 kV.

High speed response (TYP. 1Mb/s) and CMR is MIN. 15kV/ μ s.

■ Features

1. 8 pin Mini-flat package
2. Double transfer mold package
(Ideal for Flow Soldering)
3. High noise immunity due to high instantaneous common mode rejection voltage (CM_H : MIN. 15kV/ μ s, CM_L : MIN. -15kV/ μ s)
4. High speed response
(t_{PHL} : TYP. 0.2 μ s, t_{PLH} : TYP. 0.4 μ s)
5. Isolation voltage between input and output ($V_{iso(rms)}$: 3.75kV)
6. Lead-free and RoHS directive compliant

■ Agency approvals/Compliance

1. Recognized by UL1577 (Double protection isolation), file No. E64380 (as model No. **PC457S**)
2. Approved by VDE, DIN EN60747-5-2^(*) (as an option), file No. 40009162 (as model No. **PC457S**)
3. Package resin : UL flammability grade (94V-0))

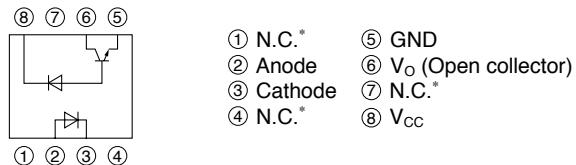
^(*) DIN EN60747-5-2 : successor standard of DIN VDE0884.

■ Applications

1. Programmable controller
2. Inverter

* "OPIC"(Optical IC) is a trademark of the SHARP Corporation. An OPIC consists of a light-detecting element and a signal-processing circuit integrated onto a single chip.

■ Internal Connection Diagram

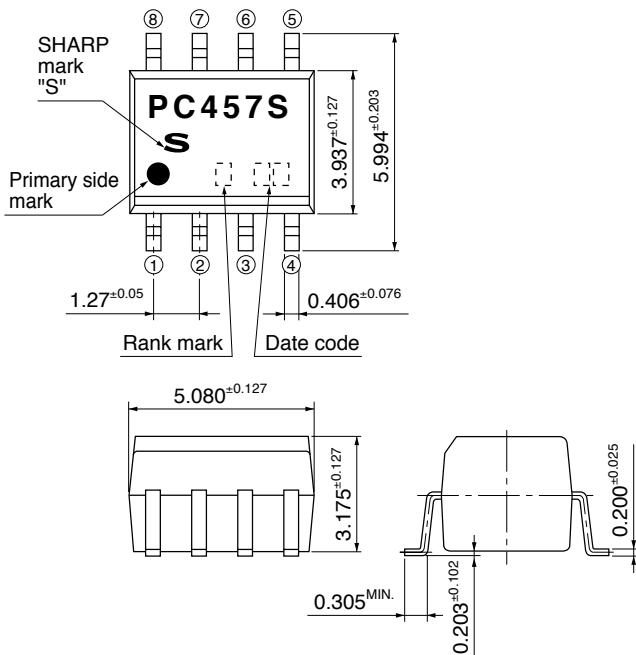


*As for N.C. pins (①, ④, ⑦), external connection is not allowed.

■ Outline Dimensions

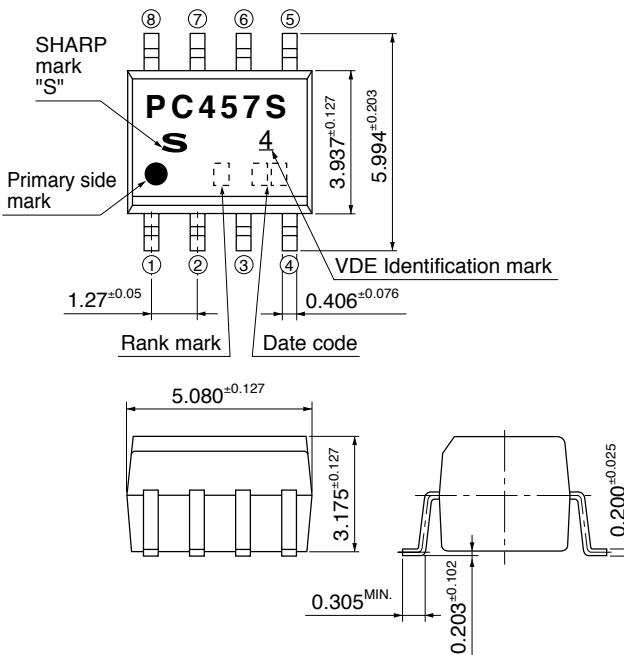
(Unit : mm)

1. Mini-flat Package [ex. PC457S0NIP0F]



Product mass : approx. 0.15g

2. Mini-flat Package (VDE option) [ex. PC457S0YIP0F]



Product mass : approx. 0.15g

Plating material : Pd (Au flush)

Date code (2 digit)

1st digit		2nd digit			
Year of production		Month of production			
A.D.	Mark	A.D.	Mark	Month	Mark
1990	A	2002	P	January	1
1991	B	2003	R	February	2
1992	C	2004	S	March	3
1993	D	2005	T	April	4
1994	E	2006	U	May	5
1995	F	2007	V	June	6
1996	H	2008	W	July	7
1997	J	2009	X	August	8
1998	K	2010	A	September	9
1999	L	2011	B	October	O
2000	M	2012	C	November	N
2001	N	:	:	December	D

repeats in a 20 year cycle

Country of origin

Japan

Rank mark

With or without.

■ Absolute Maximum Ratings

(T_a=25°C)

Parameter		Symbol	Rating	Unit
Input	* ¹ Forward current	I _F	25	mA
	Reverse input voltage	V _R	5	V
	* ² Input power dissipation	P _I	45	mW
Output	Supply voltage	V _{CC}	-0.5 to +30	V
	Output voltage	V _O	-0.5 to +20	V
	Output current	I _O	8	mA
* ³ Output power dissipation		P _O	100	mW
* ⁴ Isolation voltage		V _{iso(rms)}	3.75	kV
Operating temperature		T _{opr}	-55 to +100	°C
Storage temperature		T _{stg}	-55 to +125	°C
* ⁵ Soldering temperature		T _{sol}	270	°C

*1 When ambient temperature goes above 85°C, the forward current goes down at 0.6mA/°C. Refer to Fig.3

*2 When ambient temperature goes above 85°C, the forward current goes down at 1.1mW/°C. Refer to Fig.4

*3 When ambient temperature goes above 85°C, the forward current goes down at 2.5mW/°C. Refer to Fig.4

*4 AC for 1minute, 40 to 60%RH, f=60Hz

*5 For 10s

■ Electro-optical Characteristics

(T_a=25°C)

Parameter		Symbol	Condition	MIN.	TYP.	MAX.	Unit
Input	Input forward voltage	V _F	I _F =16mA	-	1.5	1.7	V
	* ⁷ V _F			-	-	1.8	
Reverse input voltage	I _R		V _R =5V	-	-	10	μA
Input capacitance	C _t		V _F =0, f=1MHz	-	60	-	pF
* ⁶ Output	I _{OH(1)}		I _F =0, V _{CC} =5.5V, V _O =5.5V	-	3	500	nA
	I _{OH(2)}		I _F =0, V _{CC} =15V, V _O =15V	-	0.01	1	μA
	* ⁷ I _{OH(3)}			-	-	50	
High level output current	I _{CCH(1)}		I _F =0, V _{CC} =15V, V _O =OPEN	-	0.02	1	μA
	* ⁷ I _{CCH(2)}			-	-	2	
High level supply current	I _{CCL}		I _F =16mA, V _{CC} =15V, V _O =OPEN	-	50	200	μA
Low level output voltage	V _{OL(1)}		I _F =16mA, V _{CC} =4.5V, I _O =3mA	-	-	0.4	V
	* ⁷ V _{OL(2)}		I _F =16mA, V _{CC} =4.5V, I _O =2.4mA	-	-	0.5	
Current transfer ratio	CTR(1)		I _F =16mA, V _{CC} =4.5V, V _O =0.4V	19	-	50	%
	* ⁷ CTR(2)		I _F =16mA, V _{CC} =4.5V, V _O =0.5V	15	-	-	
Transfer characteristics	t _{PHL(1)}		I _F =16mA, V _{CC} =5V, R _L =1.9kΩ	-	0.2	0.8	μs
	* ⁷ t _{PHL(2)}			-	-	1	
	t _{PLH(1)}			-	0.3	0.8	
	* ⁷ t _{PLH(2)}			-	-	1	
Instantaneous common mode rejection voltage (High level output)	C _{MH}	I _F =0, V _{O(MIN)} =2V	R _L =1.9kΩ, V _{CC} =5V,	15	30	-	kV/μs
Instantaneous common mode rejection voltage (Low level output)	C _{ML}	I _F =16mA, V _{O(MAX)} =0.8V	V _{CM} =1kV _(P-P) , C _L =15pF	-15	-30	-	kV/μs
Isolation resistance	R _{IISO}	DC500V, 40 to 60%RH		5×10 ¹⁰	10 ¹¹	-	Ω
Floating capacitance	C _f	V=0, f=1MHz		-	0.6	-	pF

*6 It shall connect a by-pass capacitor of 0.01μF or more between V_{CC} (pin ⑧) and GND (pin ⑤) near the device, when it measures the transfer characteristics and the output side characteristics*7 T_a=0 to 70°C

*8 Propagation delay time : Refer to Fig.1

*9 Instantaneous common mode rejection voltage : Refer to Fig.2

■ Model Line-up

Package	Taping	
	1 500pcs/reel	
DIN EN60747-5-2	—	Approved
Model No.	PC457S0NIP0F	PC457S0YIP0F

Please contact a local SHARP sales representative to inquire about production status.

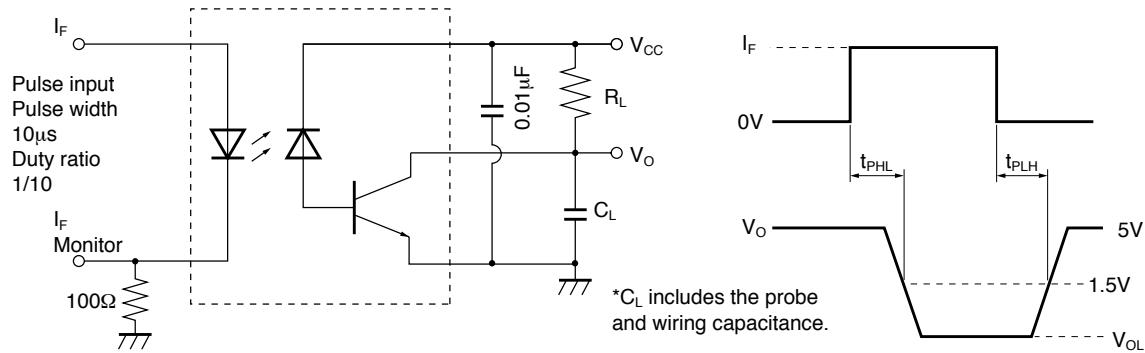
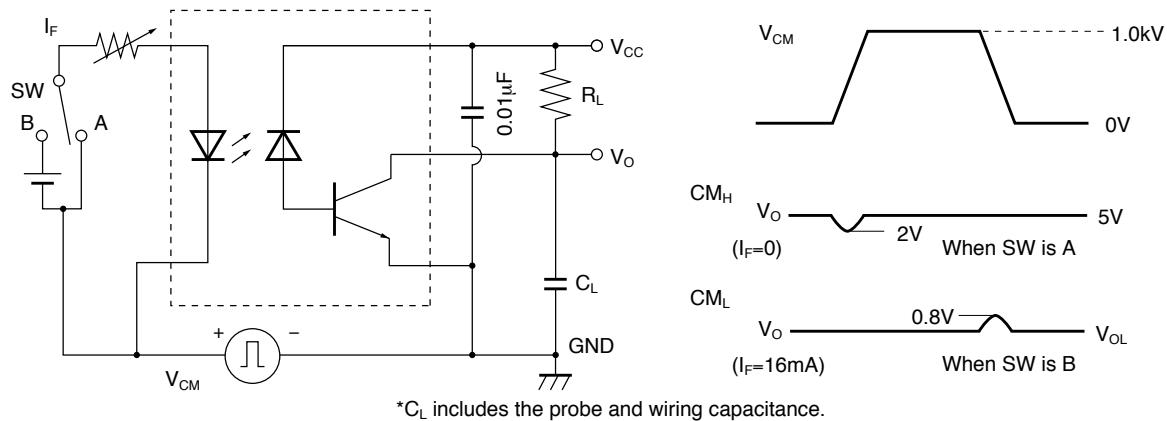
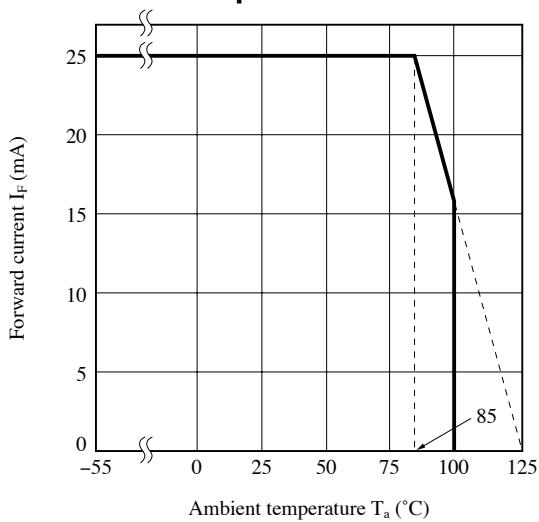
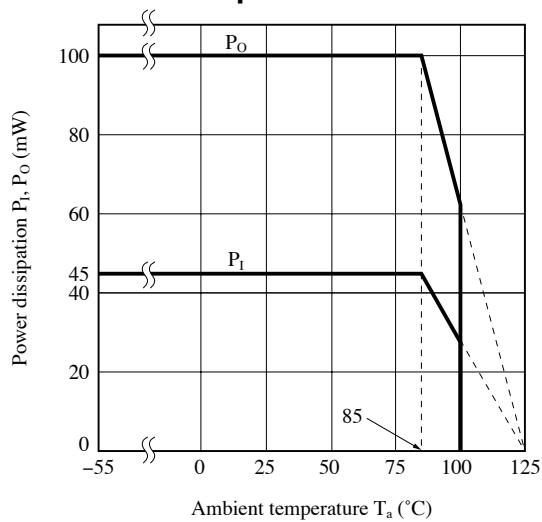
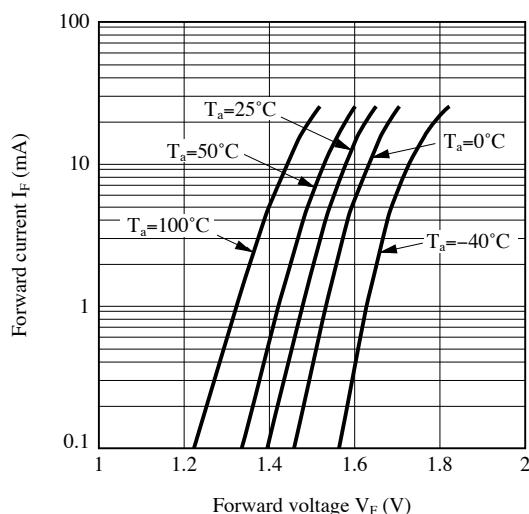
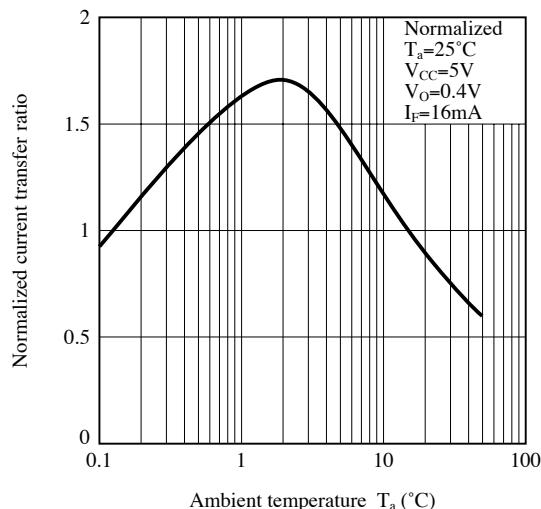
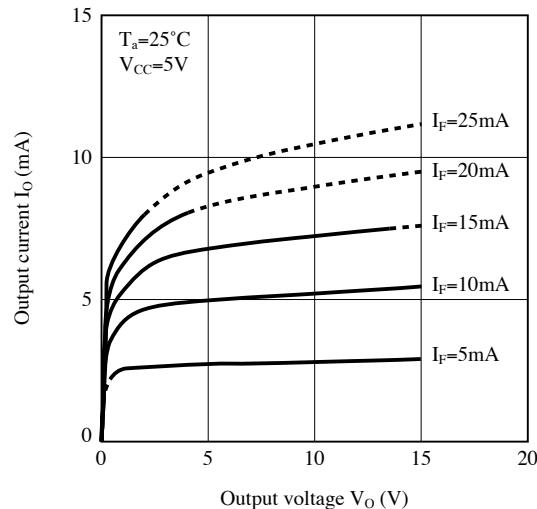
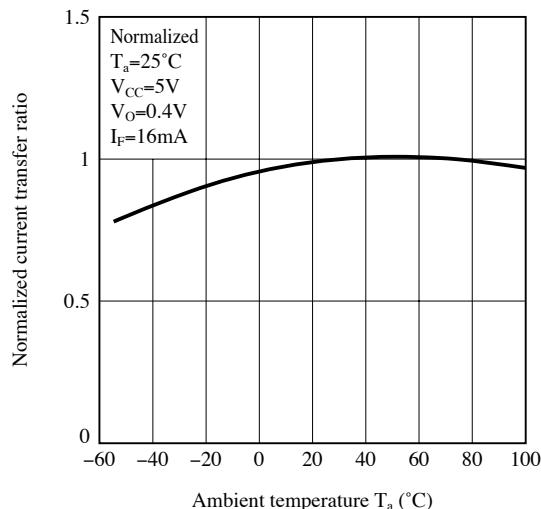
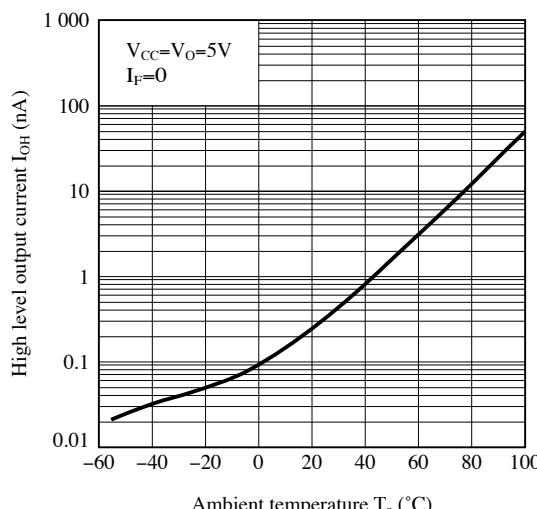
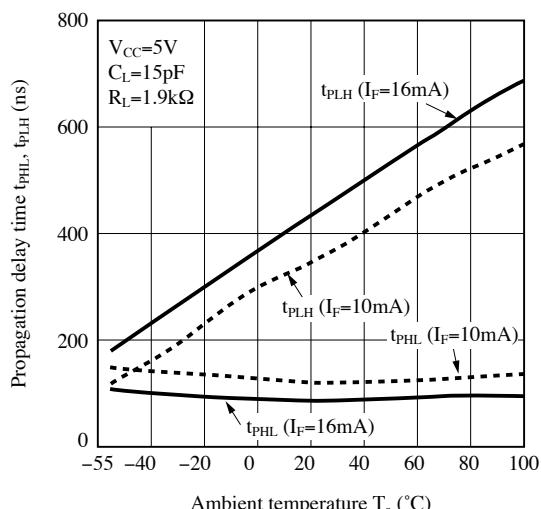
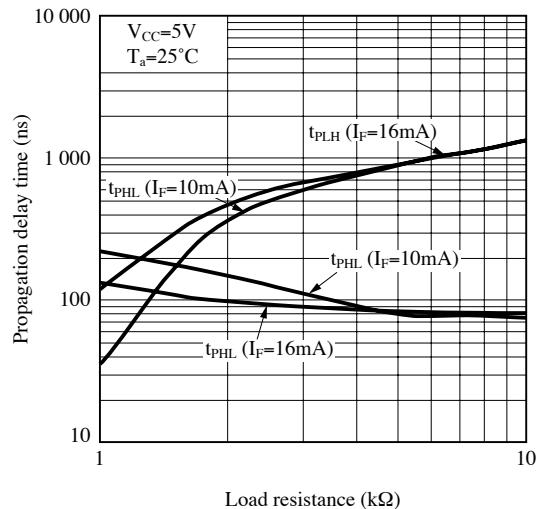
Fig.1 Test Circuit for Propagation Delay Time**Fig.2 Test Circuit for Instantaneous Common Mode Rejection Voltage****Fig.3 Forward Current vs. Ambient Temperature****Fig.4 Power Dissipation vs. Ambient Temperature**

Fig.5 Forward Current vs. Forward Voltage**Fig.6 Relative Current Transfer Ratio vs. Forward Current****Fig.7 Output Current vs. Output Voltage****Fig.8 Relative Current Transfer Ratio vs. Ambient Temperature****Fig.9 High Level Output Current vs. Ambient Temperature****Fig.10 Propagation Delay Time vs. Ambient Temperature**

**Fig.11 Propagation Delay Time vs.
Load Resistance**



Remarks : Please be aware that all data in the graph are just for reference and not for guarantee.

■ Design Considerations

● Recommended operating conditions

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Input current	I _F	7	—	16	mA
Supply voltage	V _{CC}	—	5	—	V
Operating temperature	T _{opr}	0	—	+85	°C

● Notes about static electricity

Transistor of detector side in bipolar configuration may be damaged by static electricity due to its minute design.

When handling these devices, general countermeasure against static electricity should be taken to avoid breakdown of devices or degradation of characteristics.

● Design guide

In order to stabilize power supply line, we should certainly recommend to connect a by-pass capacitor of 0.01μF or more between V_{CC} and GND near the device.

In case that some sudden big noise caused by voltage variation is provided between primary and secondary terminals of photocoupler some current caused by it is floating capacitance may be generated and result in false operation since current may go through LED or current may change.

If the photocoupler may be used under the circumstances where noise will be generated we recommend to use the bypass capacitors at the both ends of LED.

The detector which is used in this device, has parasitic diode between each pins and GND.

There are cases that miss operation or destruction possibly may be occurred if electric potential of any pin becomes below GND level even for instant.

Therefore it shall be recommended to design the circuit that electric potential of any pin does not become below GND level.

NC terminals (Pin ①, ④ and ⑦) are not allowed external connection.

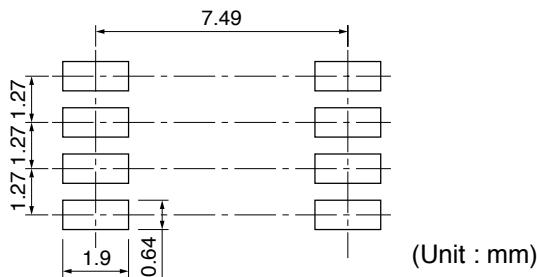
This product is not designed against irradiation and incorporates non-coherent LED.

● Degradation

In general, the emission of the LED used in photocouplers will degrade over time.

In the case of long term operation, please take the general LED degradation (50% degradation over 5 years) into the design consideration.

● Recommended foot print (reference)



■ Manufacturing Guidelines

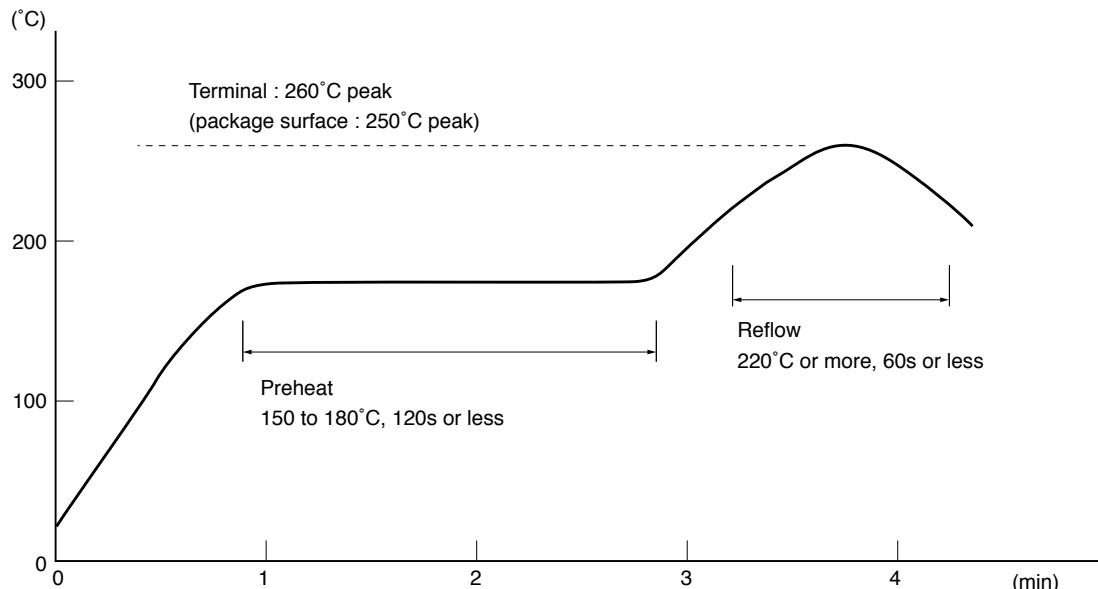
● Soldering Method

Reflow Soldering:

Reflow soldering should follow the temperature profile shown below.

Soldering should not exceed the curve of temperature profile and time.

Please don't solder more than twice.



Flow Soldering :

Due to SHARP's double transfer mold construction submersion in flow solder bath is allowed under the below listed guidelines.

Flow soldering should be completed below 270°C and within 10s.

Preheating is within the bounds of 100 to 150°C and 30 to 80s.

Please don't solder more than twice.

Hand soldering

Hand soldering should be completed within 3s when the point of solder iron is below 400°C.

Please don't solder more than twice.

Other notice

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the tooling and soldering conditions.

● Cleaning instructions

Solvent cleaning :

Solvent temperature should be 45°C or below. Immersion time should be 3 minutes or less.

Ultrasonic cleaning :

The impact on the device varies depending on the size of the cleaning bath, ultrasonic output, cleaning time, size of PCB and mounting method of the device.

Therefore, please make sure the device withstands the ultrasonic cleaning in actual conditions in advance of mass production.

Recommended solvent materials :

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol.

In case the other type of solvent materials are intended to be used, please make sure they work fine in actual using conditions since some materials may erode the packaging resin.

● Presence of ODC

This product shall not contain the following materials.

And they are not used in the production process for this product.

Regulation substances : CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBB and PBDE are not used in this product at all.

This product shall not contain the following materials banned in the RoHS Directive (2002/95/EC).

•Lead, Mercury, Cadmium, Hexavalent chromium, Polybrominated biphenyls (PBB), Polybrominated diphenyl ethers (PBDE).

● Tape and Reel package

SMT Gullwing

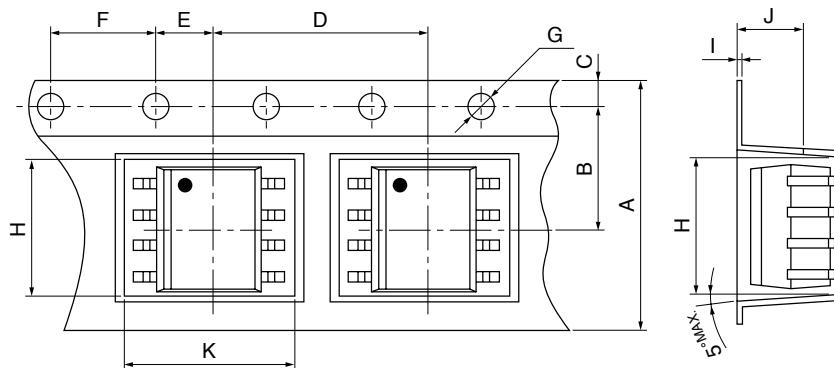
Package materials

Carrier tape : PS

Cover tape : PET (three layer system)

Reel : PS

Carrier tape structure and Dimensions

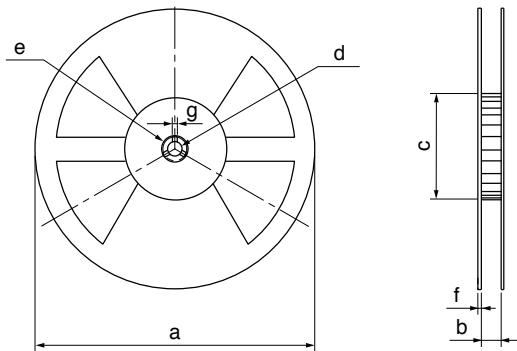


Dimensions List

(Unit : mm)

A	B	C	D	E	F	G
12.0 ± 0.3	5.50 ± 0.05	1.75 ± 0.10	8.0 ± 0.1	2.00 ± 0.05	4.0 ± 0.1	$\phi 1.55 \pm 0.05$
H	I	J	K			
5.4 ± 0.1	0.30 ± 0.05	3.7 ± 0.1	6.3 ± 0.1			

Reel structure and Dimensions

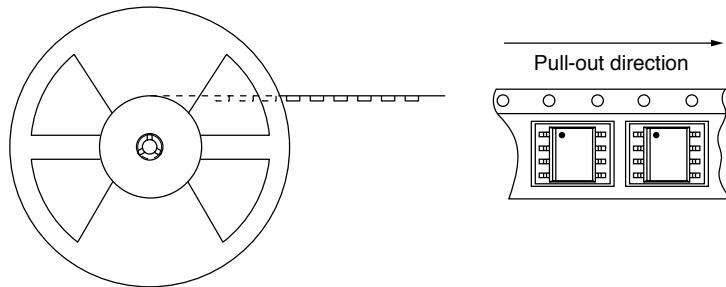


Dimensions List

(Unit : mm)

a	b	c	d
$\phi 330$	13.5 ± 1.5	$\phi 100 \pm 1$	$\phi 13.0 \pm 0.2$
e	f	g	
$\phi 21.0 \pm 0.8$	2.0 TYP.	2.0 ± 0.5	

Direction of product insertion



[Packing : 1 500pcs/reel]

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 - Test and measurement equipment
 - Industrial control
 - Audio visual equipment
 - Consumer electronics
 - (ii) Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection with equipment that requires higher reliability such as:
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 - Traffic signals
 - Gas leakage sensor breakers
 - Alarm equipment
 - Various safety devices, etc.
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